Supporting Information

Naphthalene Flanked Diketopyrrolopyrrole Based Organic Semiconductors for High Performance Organic Field Effect Transistors

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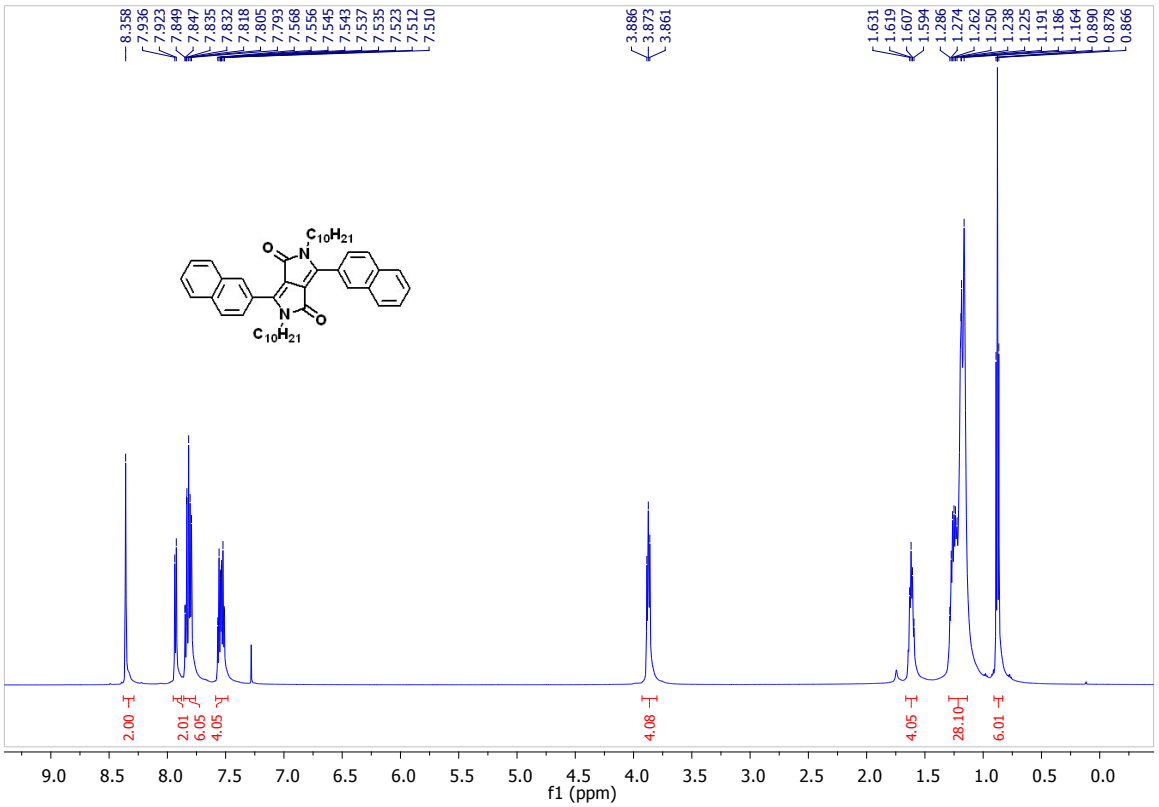

Figure S1. ^{1}H NMR spectrum of D-DPPN.

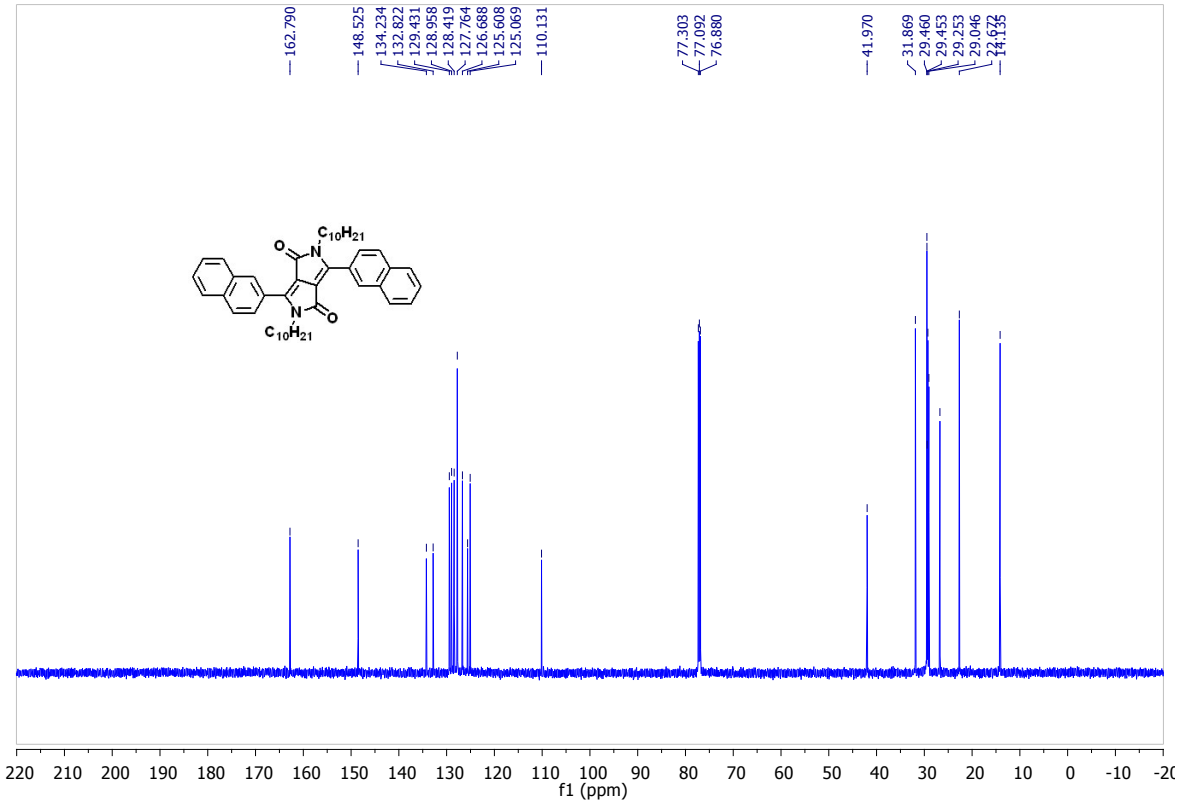

Figure S2. ^{13}C NMR spectrum of D-DPPN.

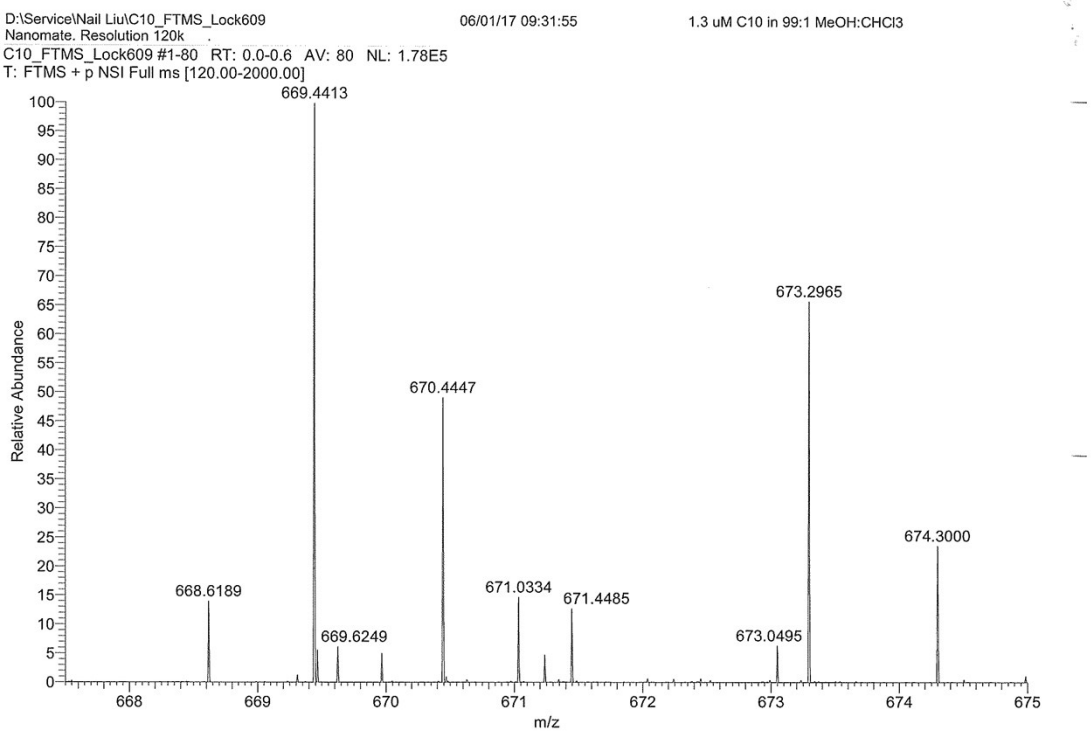

Figure S3. HRMS spectrum of D-DPPN.

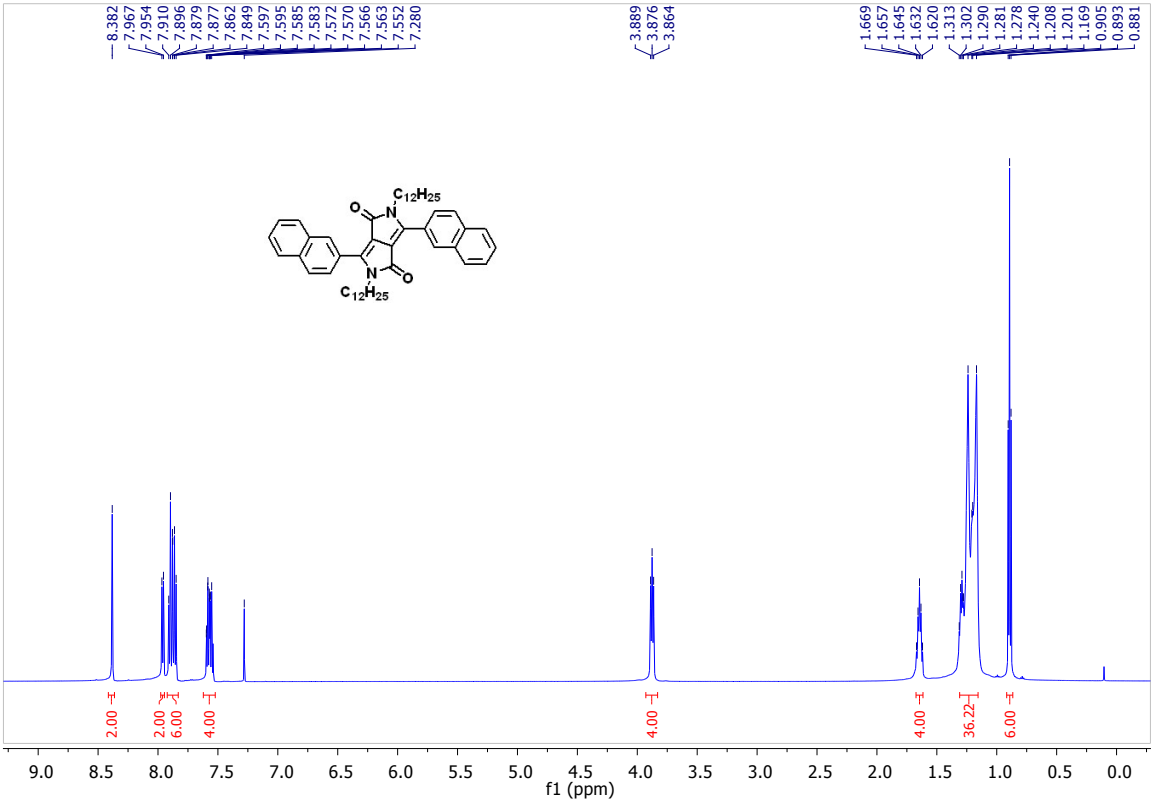

Figure S4. ^{1}H NMR spectrum of DD-DPPN.

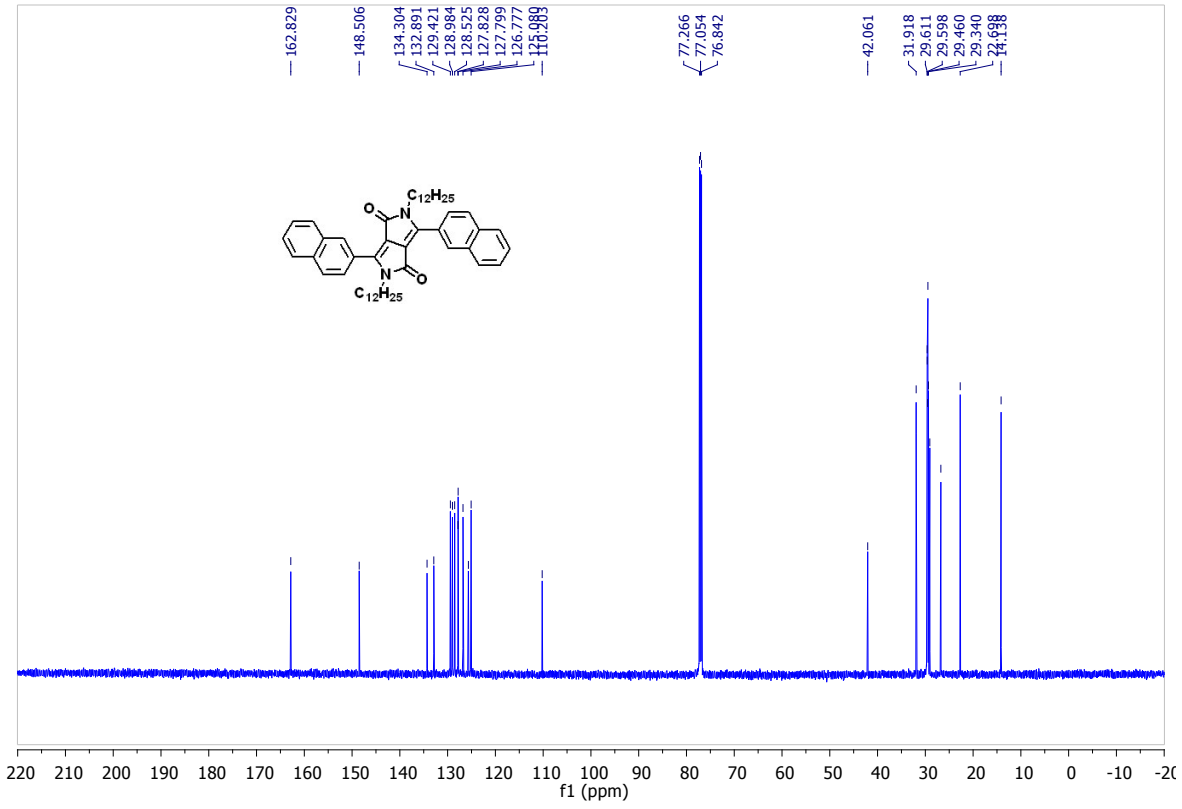

Figure S5. ^{13}C NMR spectrum of DD-DPPN.

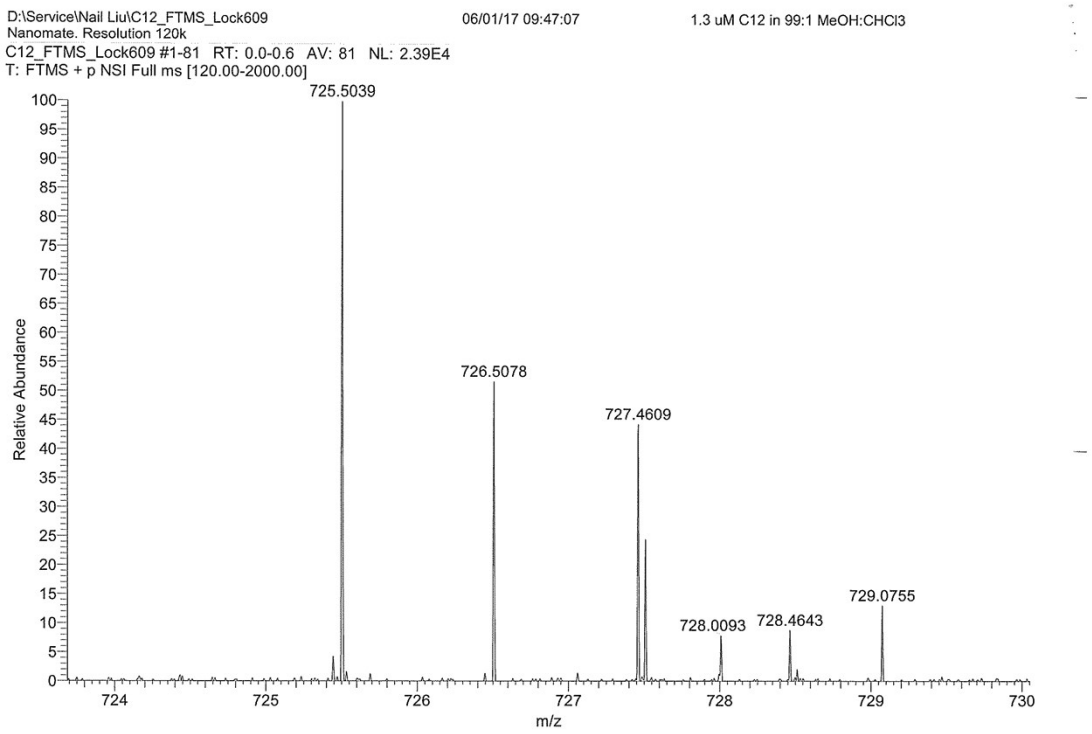

Figure S6. HRMS spectrum of DD-DPPN.

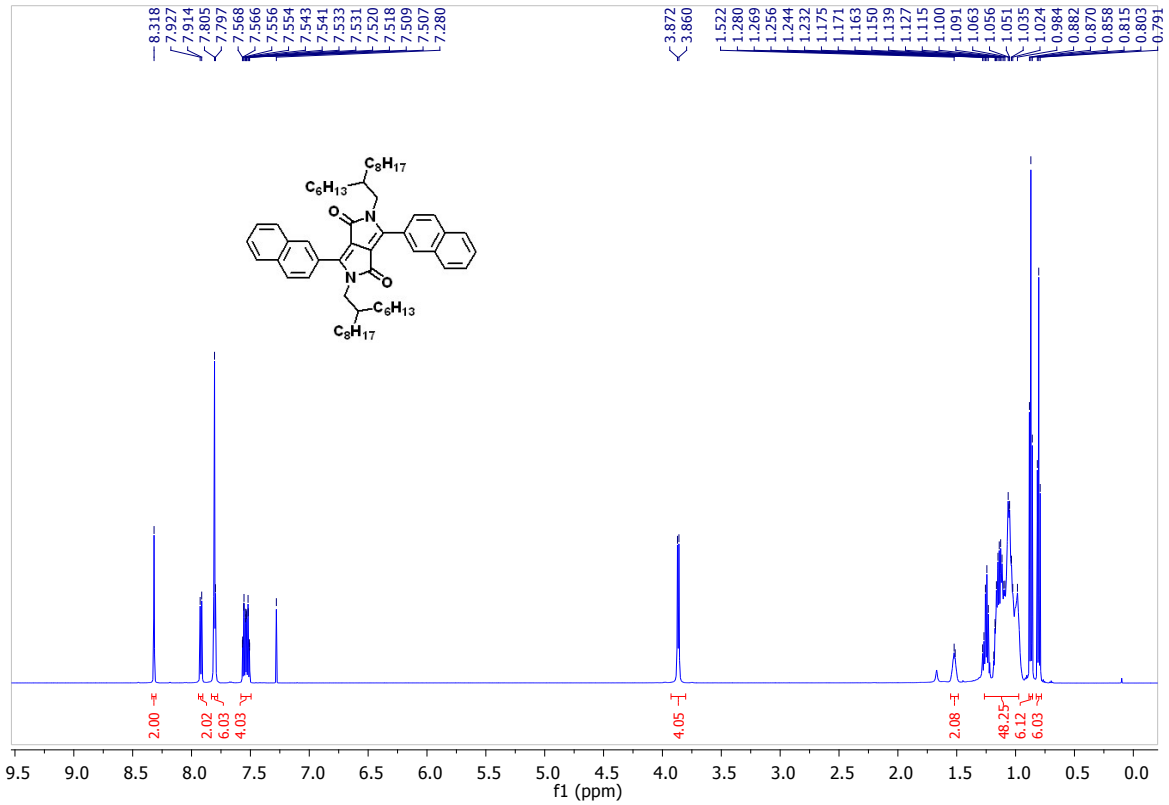

Figure S7. ^{1}H NMR spectrum of HD-DPPN.

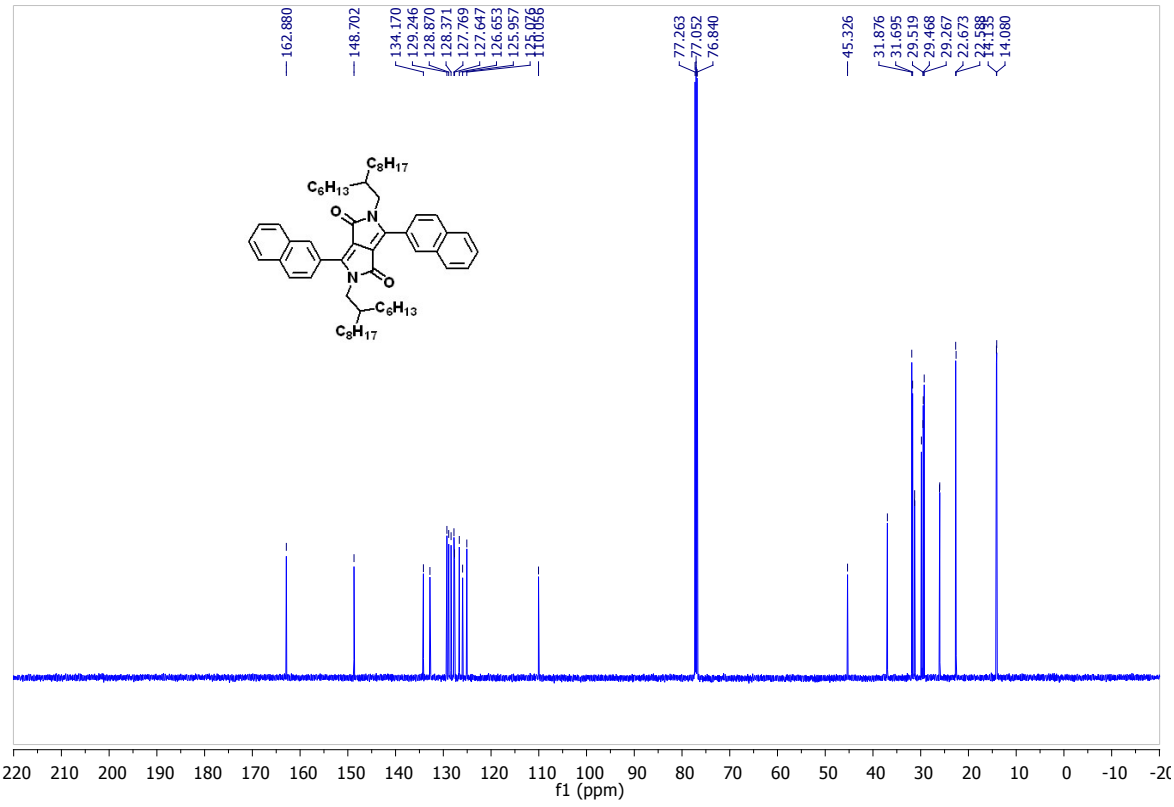

Figure S8. ^{13}C NMR spectrum of HD-DPPN.

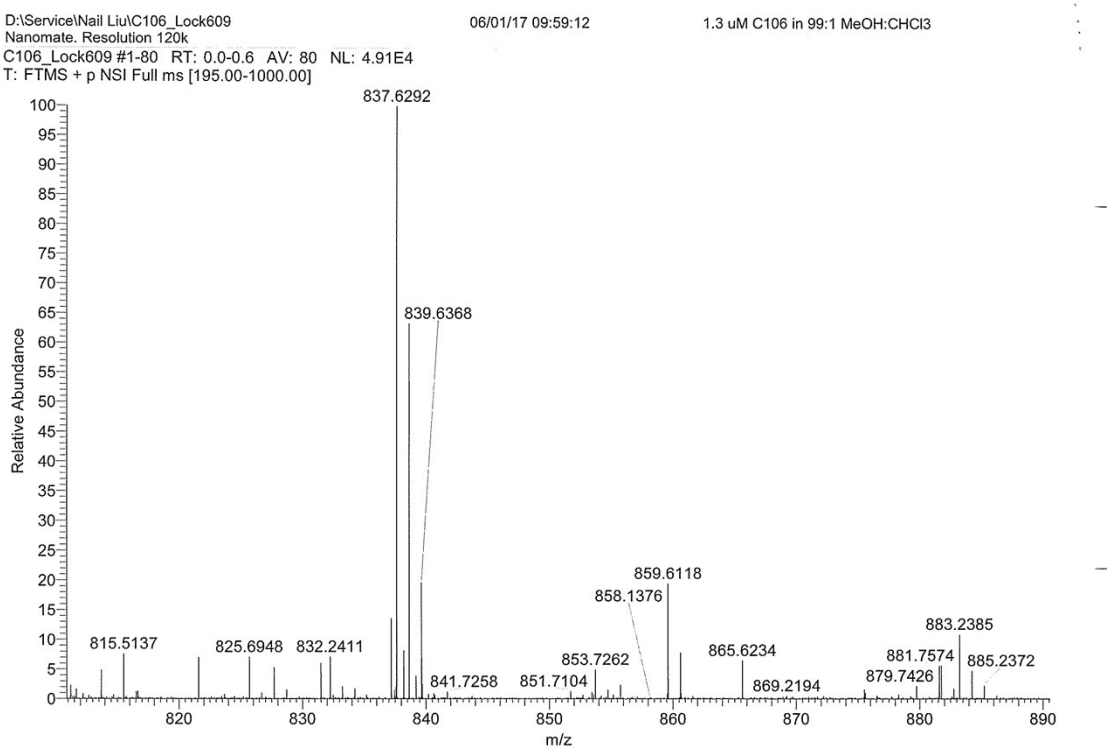

Figure S9. HRMS spectrum of HD-DPPN.

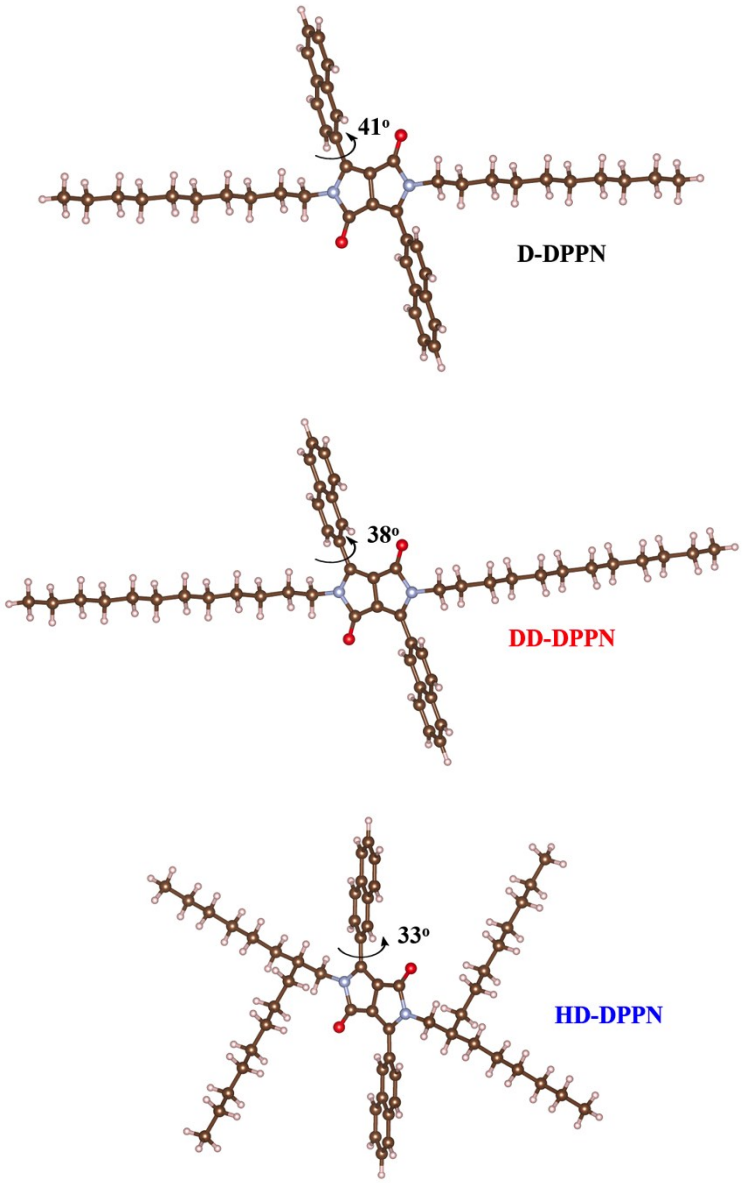

Figure S10. Side view of D-DPPN, DD-DPPN and HD-DPPN.

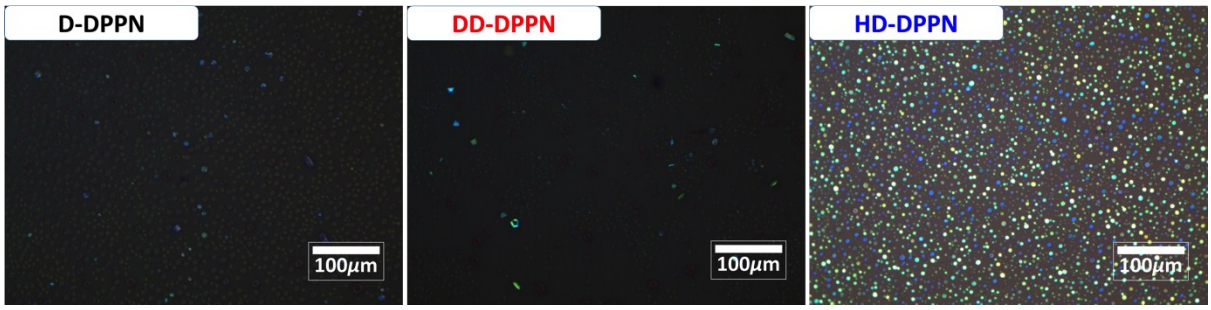

Figure S11. Polarized microscope images of D-DPPN, DD-DPPN and HD-DPPN thin films after 150 °C annealing.